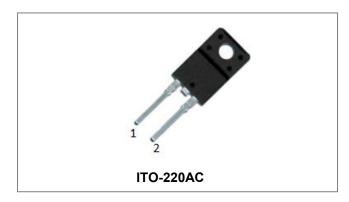


MBRF1040

Technical Data Data Sheet N0630, Rev. B



MBRF1040 SCHOTTKY RECTIFIER



Features

- 150 °C T_J operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

- Switching power supply
- Converters
- **Free-Wheeling diodes**
- **Reverse battery protection**
- Center tap configuration

Maximum Ratings:

| Characteristics Symbol | | Condition | Max. | Units |
|--|--|---|------|-------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V _{RRM} V _{RWM} V _R | - | 40 | V |
| Average Rectified Forward Current | I _{F (AV)} | 50% duty cycle @Tc=125°C, rectangular wave form | 10 | А |
| Peak One Cycle Non-Repetitive Surge Current | I _{FSM} | 8.3ms, Half Sine pulse | 150 | А |

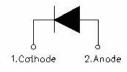
Electrical Characteristics:

| Characteristics | Symbol | Condition | Тур. | Max. | Units |
|----------------------------------|-----------------|---|------|--------|-------|
| Forward Voltage Drop* | V _{F1} | @ 10A, Pulse, TJ = 25 ℃ | 0.58 | 0.84 | V |
| Reverse Current at DC condition* | I _{R1} | $@V_R = rated V_{R,} T_J = 25$ °C | 0.28 | 1.0 | mA |
| | I _{R2} | @V _R = rated V _R , T _J = 125 °C | 7 | 15 | mA |
| Junction Capacitance | Ст | @V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz | 380 | 450 | pF |
| Typical Series Inductance | Ls | Measured lead to lead 5 mm from package body | 8.0 | - | nH |
| Voltage Rate of Change | dv/dt | - | - | 10,000 | V/μs |

Pulse width < 300 µs, duty cycle < 2%

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Circuit Diagram





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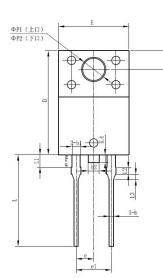
RoHS 🗭

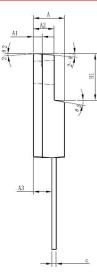
Thermal-Mechanical Specifications:

| Characteristics | Symbol | Condition | Specification | Units |
|---|------------------|--------------|---------------|-------|
| Junction Temperature | TJ | - | -55 to +150 | °C |
| Storage Temperature | T _{stg} | - | -55 to +150 | °C |
| Typical Thermal Resistance Junction to Case | Rejc | DC operation | 2.5 | °C/W |
| Approximate Weight | wt | - | 1.6 | g |
| Case Style | ITO-220AC | | | |

Mechanical Dimensions ITO-220AC

~

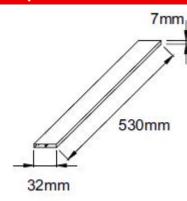




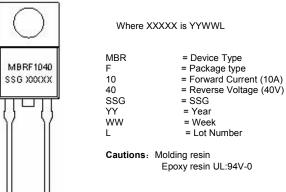
| | Millimeters | | | | |
|-----------------|-------------|-------|-------|--|--|
| SYMBOL | MIN. | TYP. | MAX. | | |
| A | 4.30 | 4.50 | 4.70 | | |
| A1 | 1.10 | 1.30 | 1.50 | | |
| A2 | 2.80 | 3.00 | 3.20 | | |
| A3 | 2.50 | 2.70 | 2.90 | | |
| b | 0.50 | 0.60 | 0.75 | | |
| b1 | 1.10 | 1.20 | 1.35 | | |
| b2 | 1.50 | 1.60 | 1.75 | | |
| С | 0.55 | 0.60 | 0.75 | | |
| D | 14.80 | 15.00 | 15.20 | | |
| E | 9.96 | 10.16 | 10.36 | | |
| е | - | 2.55 | - | | |
| e1 | - | 5.10 | - | | |
| H1 | 6.50 | 6.70 | 6.90 | | |
| L | 12.70 | 13.20 | 13.70 | | |
| L1 | 1.60 | 1.80 | 2.00 | | |
| L2 | 0.80 | 1.00 | 1.20 | | |
| L3 | 0.60 | 0.80 | 1.00 | | |
| L4 | - | 1.10 | 1.50 | | |
| ΦΡ1 (上口) | 3.30 | 3.50 | 3.70 | | |
| ΦΡ2 (下口) | 2.99 | 3.19 | 3.39 | | |
| Q | 2.50 | 2.70 | 2.90 | | |
| Θ1 | | 5° | | | |
| Θ2 | | 4° | | | |
| Θ3 | | 10° | | | |
| Θ4 | | 5° | | | |
| Θ5 | | 5° | | | |



Tube Specification



Marking Diagram



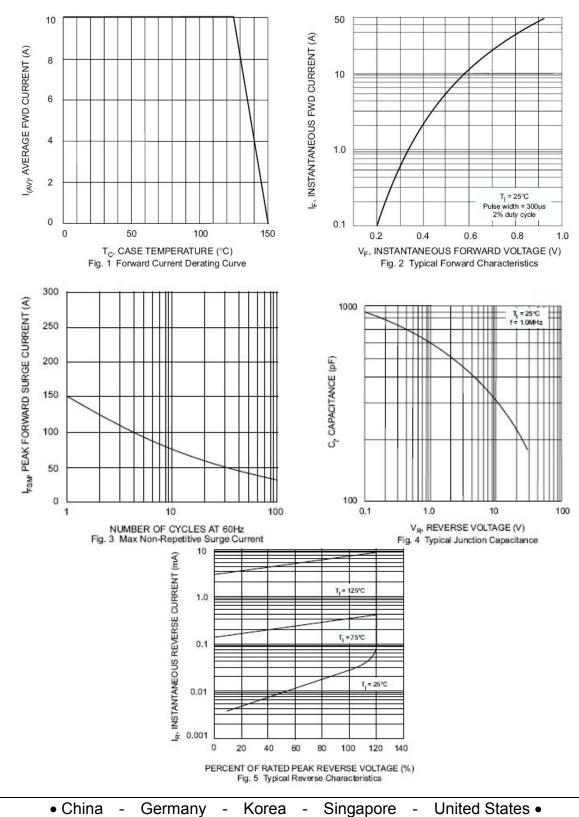
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Ratings and Characteristics Curves



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MBRF1040



Ordering Information

| Device | Package | Shipping | |
|----------|---------------------|--------------|--|
| MBRF1040 | ITO-220AC (Pb-Free) | 50 pcs/ tube | |

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

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